

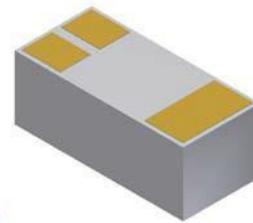
Ultra Low capacitance double Uni-directional ESD protection diodes

The MESD05N92ULA device is characterized by their ultra low capacitance, low operating and clamping voltages, and fast response time. This makes it ideal for use as board level protection of sensitive semiconductor components. The dual-junction common-anode design allows the user to protect two bidirectional lines.

It has been specifically designed to protect sensitive components which are connected to data and transmission lines from overvoltage caused by ESD(electrostatic discharge), CDE (Cable Discharge Events),and EFT (electrical fast transients).

Features

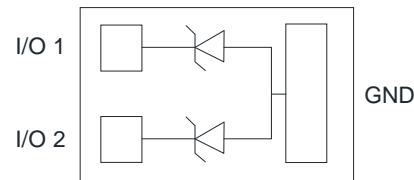
- Ultra small package(DFN1006) for use in portable electronics
- ESD protection of two lines
- Ultra Low leakage current
- Ultra Low capacitance: $C_J=0.45\text{pF}$ typ
- Response Time is < 1 ns
- Working voltages :5.5V
- Solid-state silicon avalanche technology
- Device Meets MSL 1 Requirements
- ROHS compliant



DFN1006-3L

Main applications

- USB1.1/2.0/3.0/3.1 Data lines
- HDMI 2.0
- Industrial Controls
- Computers and peripherals
- Portable instrumentation
- Notebook Computers
- DVI
- Projection TV
- Audio and video equipment
- Subscriber Identity Module (SIM) card protection



Protection solution to meet

- IEC61000-4-2 (ESD): $\pm 15\text{kV}$ (air), $\pm 8\text{kV}$ (contact)
- IEC61000-4-4 (EFT): 40A (5/50ns)

Ordering Information

| Device | Qty per Reel | Reel Size |
|--------------|--------------|-----------|
| MESD05N92ULA | 10000 | 7 Inch |



Maximum ratings (Tamb=25°C Unless Otherwise Specified)

| Parameter | Symbol | Value | Unit |
|------------------------------|------------------|---------------|------|
| ESD Rating per IEC61000-4-2: | Contact | 15 | KV |
| | Air | 15 | |
| Lead Soldering Temperature | T _L | 260 (10 sec.) | °C |
| Operating Temperature Range | T _J | -55 ~ 150 | °C |
| Storage Temperature Range | T _{TSG} | -55 ~ 150 | °C |

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

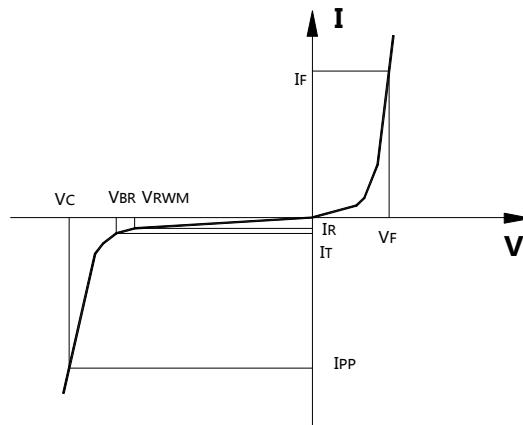
*Other voltages may be available upon request.

1. Non-repetitive current pulse, per Figure 1.

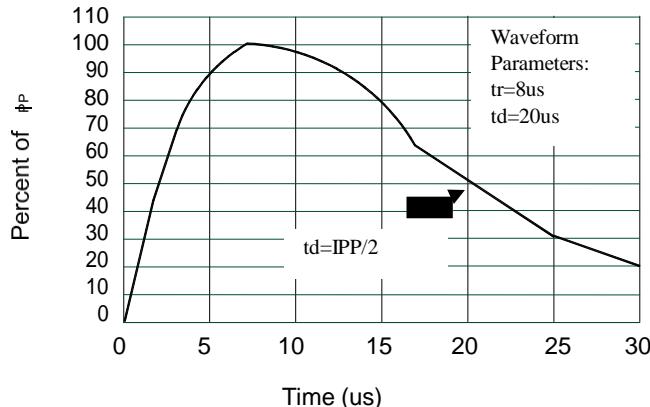
Electrical characteristics (Tamb=25°C Unless Otherwise Specified)

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Units |
|------------------|---------------------------|---|------|------|------|-------|
| V _{RWM} | Reverse Working Voltage | any I/O pin to Ground | | | 5.5 | V |
| V _{BR} | Reverse Breakdown Voltage | I _T =0.1mA | 6.0 | | | V |
| I _{RM} | Reverse Leakage Current | V _{RWM} =5.5V | | | 0.1 | uA |
| V _F | Forward Voltage | I _T = 15mA Pin3 to Pin1、Pin2 | | 0.9 | 1.2 | V |
| V _C | Clamping Voltage | I _{PP} =3A, t _P =8/20μs; | | | 9.8 | V |
| C _J | Junction Capacitance | V _R =0V, f = 1MHz Any I/O pin to Ground | | 0.45 | 0.65 | pF |

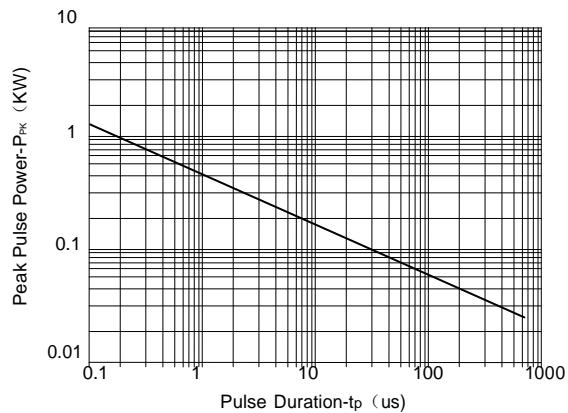
| Symbol | Parameter |
|------------------|-------------------------------------|
| V _{RWM} | Working Peak Reverse Voltage |
| V _{BR} | Breakdown Voltage @ I _T |
| V _C | Clamping Voltage @ I _{PP} |
| I _T | Test Current |
| I _{RM} | Leakage current at V _{RWM} |
| I _{PP} | Peak pulse current |
| C _O | Off-state Capacitance |
| C _J | Junction Capacitance |



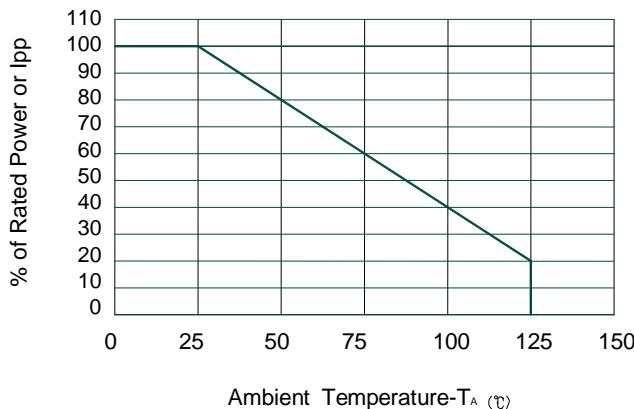
Typical electrical characterist applications



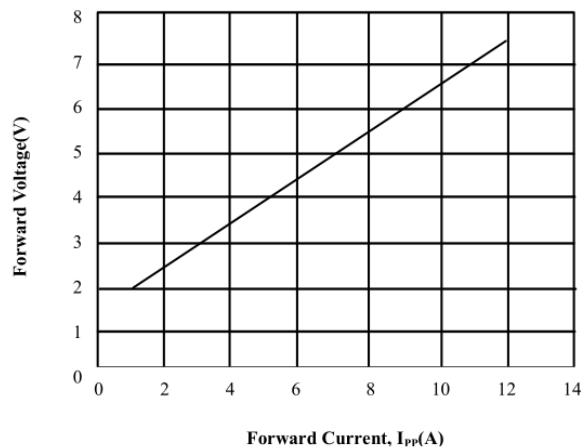
Pulse Waveform



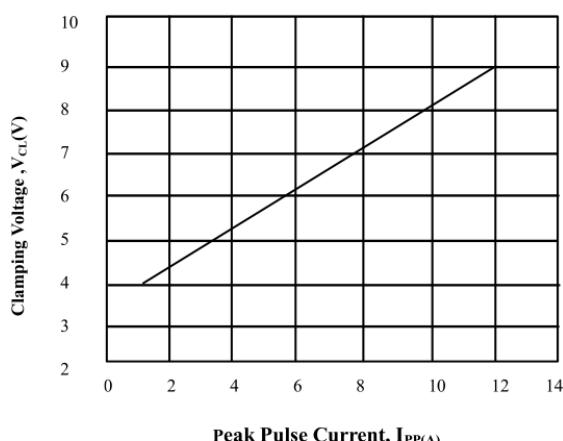
Non-Repetitive Peak Pulse Power vs. Pulse Time



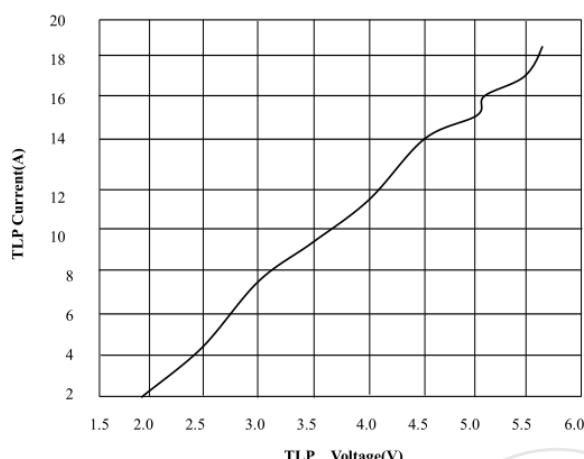
Power Derating Curve



Forward Voltage vs. Forward Peak Pulse Current
($t_{period}=100\text{ns}, t_r=1\text{ns}$)



Clamping Voltage vs. Peak Pulse Current
($t_{period}=100\text{ns}, t_r=1\text{ns}$)



Transmission Line Pulsing (TLP) Measurement



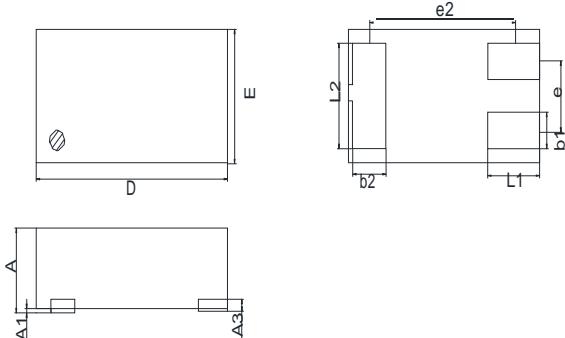
Package information

DFN1006-3L

Mechanical Data

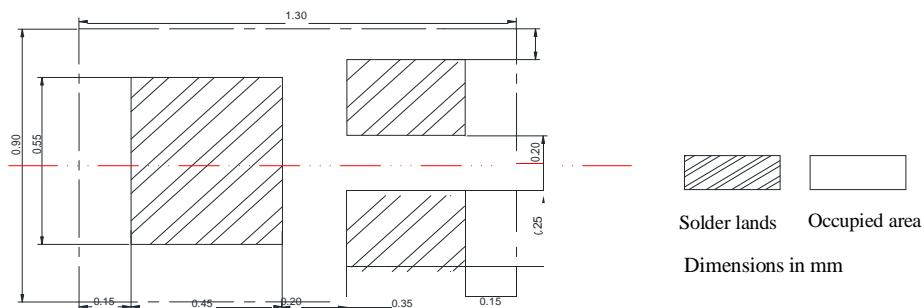
Case: DFN1006-3L

Case Material: Molded Plastic. UL Flammability

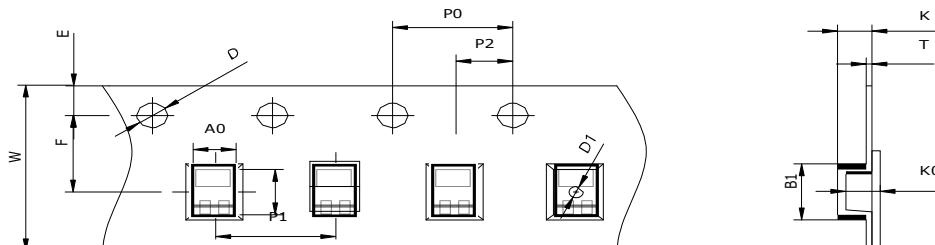


| Dim | Millimeters | | Inches | |
|-----|-------------|------|----------|-------|
| | Min | Max | Min | Max |
| A | 0.40 | 0.55 | 0.016 | 0.022 |
| A1 | 0.01 | 0.10 | 0.0004 | 0.004 |
| A3 | 0.125REF | | 0.005REF | |
| D | 0.95 | 1.05 | 0.037 | 0.041 |
| E | 0.55 | 0.65 | 0.022 | 0.026 |
| b1 | 0.10 | 0.20 | 0.004 | 0.008 |
| b2 | 0.20 | 0.30 | 0.008 | 0.012 |
| L1 | 0.20 | 0.40 | 0.008 | 0.016 |
| L2 | 0.40 | 0.60 | 0.016 | 0.024 |
| e1 | 0.30 | 0.40 | 0.012 | 0.016 |
| e2 | 0.675BSC | | 0.027BSC | |

Pad Layout



DFN1006-3L Reel Dim



| Package | Chip Size (mm) | Pocket Size B0xA0xK0(mm) | Tape Width | Reel Diameter | Quantity Per Reel | P0 | P1 |
|------------|----------------|--------------------------|------------|---------------|-------------------|-----|-----|
| DFN1006-3L | 1.55×1.45×0.55 | 1.65×1.55×0.65 | 8mm | 178mm(7") | 10000 | 4mm | 2mm |
| D0 | D1 | E | F | K | T | | W |
| 1.5mm | - | 1.75mm | 3.5mm | 0.60mm | 0.3mm | | 8mm |